

**INDUSTRY STANDARD OF THE
PEOPLE'S REPUBLIC OF CHINA**

SJ 797-1974

**Detail specification for silicon NPN epitaxial planar high
frequency low power high reverse voltage transistors, Type
3DG161**

**3DG161型NPN硅平面高频小功率高反压三极管
(English Translation)**

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What this standard covers

This standard applies to 3DG161 silicon NPN planar high frequency low power semiconductor transistor backpressure. The product is used in electronic devices for switching and high frequency amplification and oscillation.

Document data

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